

Fast Recovery Diodes (T-Modules), 40 A, 70 A, 85 A


D-55 (T-module)

FEATURES

- Fast recovery time characteristics
- Electrically isolated base plate
- 3500 V_{RMS} isolating voltage
- Standard JEDEC® package
- Simplified mechanical designs, rapid assembly
- Large creepage distances
- UL E78996 approved
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

DESCRIPTION

The series of T-modules uses fast recovery power diodes in a single diode configuration. The semiconductors are electrically isolated from the metal base, allowing common heatsink and compact assemblies to be built.

These single diode modules can be used in conjunction with the thyristor modules as a freewheel diode. Application includes self-commutated inverters, DC choppers, motor control, inductive heating and electronic welders. These modules are intended for those applications where very fast recovery characteristics are required and for general power switching applications.

PRIMARY CHARACTERISTICS

I _{F(AV)}	40 A, 70 A, 85 A
Type	Modules - diode, fast
V _{RRM}	100 V to 1000 V
Package	D-55 (T-module)
Circuit configuration	Single

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES			UNITS
		T40HFL	T70HFL	T85HFL	
I _{F(AV)}		40	70	85	A
	T _C	70	70	70	°C
I _{F(RMS)}		63	110	133	A
I _{FSM}	50 Hz	475	830	1300	A
	60 Hz	500	870	1370	
I ² t	50 Hz	1130	3460	8550	A ² s
	60 Hz	1030	3160	7810	
V _{RRM}	Range	100 to 1000			V
t _{rr}	Range	200 to 1000			ns
T _J	Range	-40 to +125			°C

ELECTRICAL SPECIFICATIONS
VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	t _{rr} CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 25 °C μA
VS_T40HFL.. VS_T70HFL.. VS_T85HFL..	10	S02, S05, S10	100	150	100
	20	S02, S05, S10	200	300	
	40	S02, S05, S10	400	500	
	60	S02, S05, S10	600	700	
	80	S05, S10	800	900	
	100	S05, S10	1000	1100	



FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES			UNITS
					T40HFL	T70HFL	T85HFL	
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave			40	70	85	A
					70			°C
Maximum RMS forward current	$I_{F(RMS)}$				63	110	133	A
Maximum peak, one-cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	475	830	1300	A
		t = 8.3 ms			500	870	1370	
		t = 10 ms	100 % V_{RRM} reappplied		400	700	1100	
		t = 8.3 ms			420	730	1150	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied		1130	3460	8550	A ² s
		t = 8.3 ms			1030	3160	7810	
		t = 10 ms	100 % V_{RRM} reappplied		800	2450	6050	
		t = 8.3 ms			730	2230	5520	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reappplied			11 300	34 600	85 500	A ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	$T_J = 25\text{ °C}$, $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$			0.82	0.87	0.84	V
High level value of threshold voltage	$V_{F(TO)2}$	$T_J = 25\text{ °C}$, $(I > \pi \times I_{F(AV)})$			0.84	0.90	0.86	
Low level value of forward slope resistance	r_{f1}	$T_J = 25\text{ °C}$, $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$			7.0	2.77	2.15	mΩ
High level value of forward slope resistance	r_{f2}	$T_J = 25\text{ °C}$, $(I > \pi \times I_{F(AV)})$			6.8	2.67	2.07	
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25\text{ °C}$, $t_p = 400\text{ }\mu\text{s}$ square wave Average power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$			1.60	1.73	1.55	V

REVERSE RECOVERY CHARACTERISTICS												
PARAMETER	SYMBOL	TEST CONDITIONS (1)	T40HFL			T70HFL			T85HFL			UNITS
			S02	S05	S10	S02	S05	S10	S02	S05	S10	
Maximum reverse recovery time	t_{rr}	$T_J = 25\text{ °C}$, $-di_F/dt = 100\text{ A}/\mu\text{s}$ $I_F = 1\text{ A}$ to $V_R = 30\text{ V}$	70	110	270	70	110	270	80	120	290	ns
		$T_J = 25\text{ °C}$, $-di_F/dt = 25\text{ A}/\mu\text{s}$ $I_{FM} = \pi \times \text{rated } I_{F(AV)}$, $V_R = -30\text{ V}$	200	500	1000	200	500	1000	200	500	1000	
Maximum reverse recovery charge	Q_{rr}	$T_J = 25\text{ °C}$, $-di_F/dt = 100\text{ A}/\mu\text{s}$ $I_F = 1\text{ A}$ to $V_R = 30\text{ V}$	0.25	0.4	1.35	0.25	0.4	1.35	0.3	0.6	1.6	μC
		$T_J = 25\text{ °C}$, $-di_F/dt = 25\text{ A}/\mu\text{s}$ $I_{FM} = \pi \times \text{rated } I_{F(AV)}$, $V_R = -30\text{ V}$	0.55	2.0	8.0	0.6	2.1	8.5	0.8	3.5	1.5	

Note

(1) Tested on LEM 300 A diodemeter tester

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	T40HFL	T70HFL	T85HFL	UNITS
Maximum peak reverse leakage current	I_{RRM}	$T_J = 125\text{ °C}$	20			mA
RMS isolation voltage	V_{ISOL}	50 Hz, circuit to base, all terminals shorted, $T_J = 25\text{ °C}$, $t = 1\text{ s}$	3500			V



THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Junction operating temperature range	T_J			-40 to +125	°C
Storage temperature range	T_{Stg}			-40 to +150	
Maximum internal thermal resistance, junction to case per module	R_{thJC}	DC operation	T40HFL	0.85	K/W
			T70HFL	0.53	
			T85HFL	0.46	
Thermal resistance, case to heatsink per module	R_{thCS}		Mounting surface, flat, smooth and greased	0.2	
Mounting torque $\pm 10\%$	base to heatsink	Non-lubricated threads	M3.5 mounting screws ⁽¹⁾	$1.3 \pm 10\%$	Nm
	busbar to terminal		M5 screws terminals	$3 \pm 10\%$	
Approximate weight			See dimensions - link at the end of datasheet	54	g
				19	oz.
Case style				D-55 (T-module)	

Note

⁽¹⁾ A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound

ΔR CONDUCTION											
DEVICES	SINUSOIDAL CONDUCTION AT T_J MAXIMUM					RECTANGULAR CONDUCTION AT T_J MAXIMUM					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
T40HFL	0.06	0.08	0.10	0.14	0.24	0.05	0.08	0.10	0.15	0.24	K/W
T70HFL	0.05	0.06	0.08	0.11	0.19	0.04	0.06	0.08	0.12	0.19	
T85HFL	0.04	0.05	0.06	0.09	0.15	0.03	0.05	0.07	0.09	0.15	

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

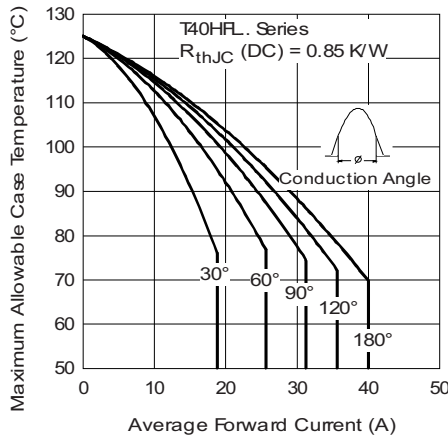


Fig. 1 - Current Ratings Characteristics

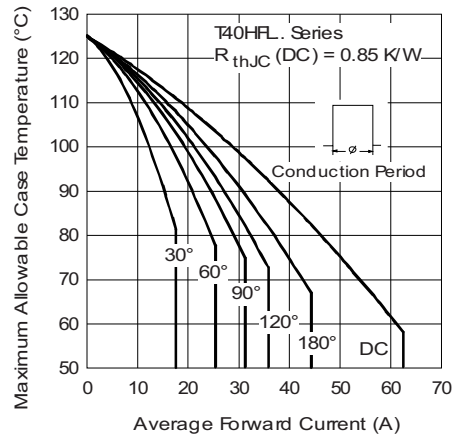


Fig. 2 - Current Ratings Characteristics

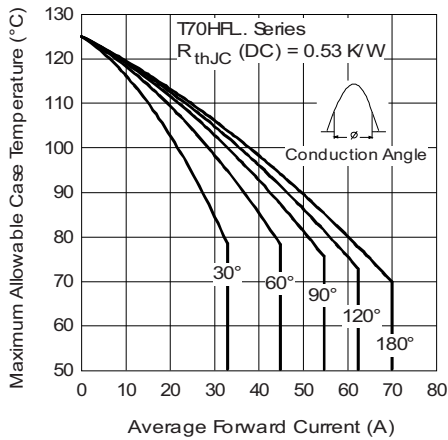


Fig. 3 - Current Ratings Characteristics

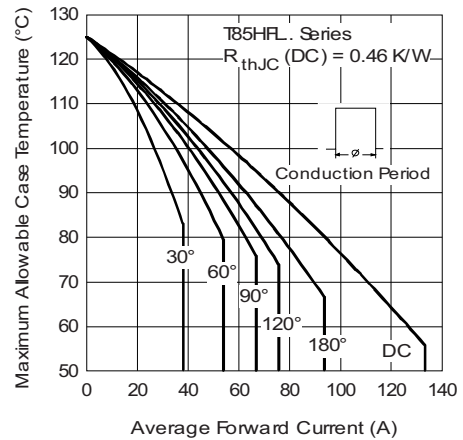


Fig. 6 - Current Ratings Characteristics

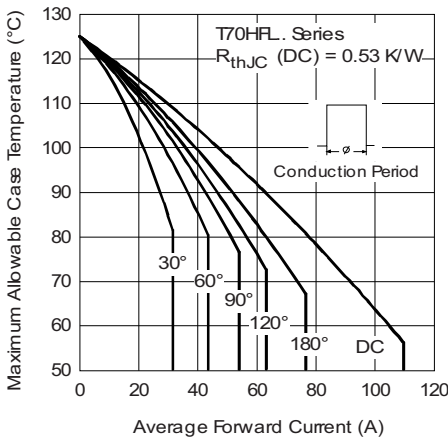


Fig. 4 - Current Ratings Characteristics

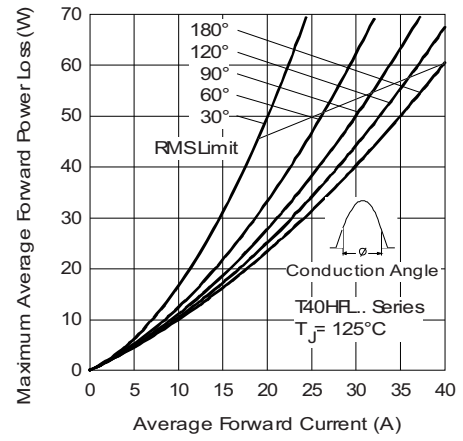


Fig. 7 - Forward Power Loss Characteristics

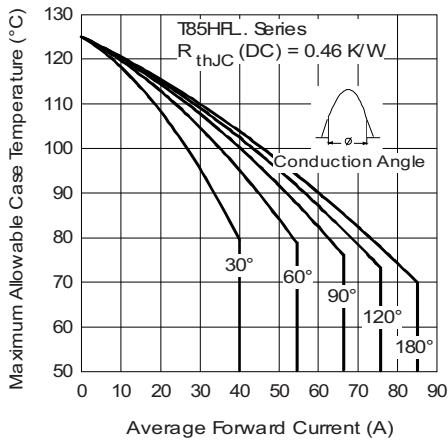


Fig. 5 - Current Ratings Characteristics

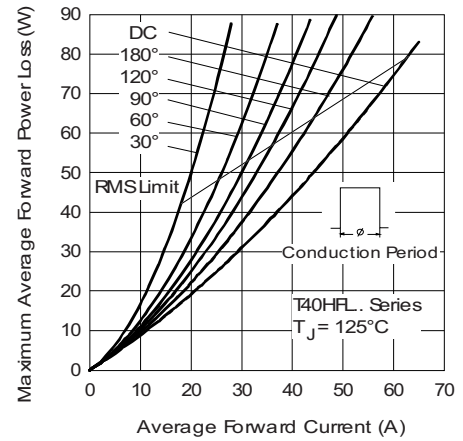


Fig. 8 - Forward Power Loss Characteristics

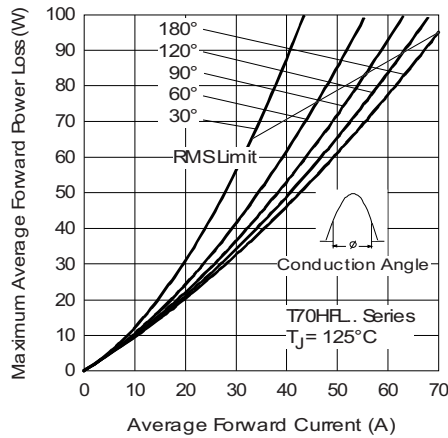


Fig. 9 - Forward Power Loss Characteristics

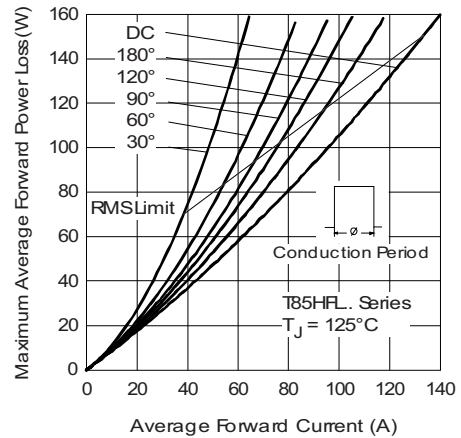


Fig. 12 - Forward Power Loss Characteristics

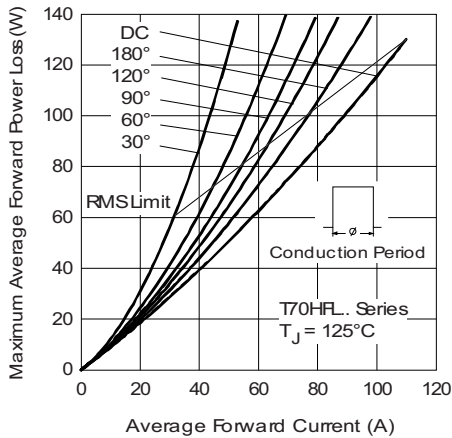


Fig. 10 - Forward Power Loss Characteristics

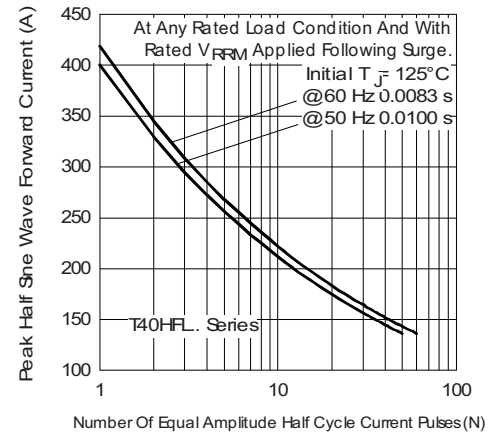


Fig. 13 - Maximum Non-Repetitive Surge Current

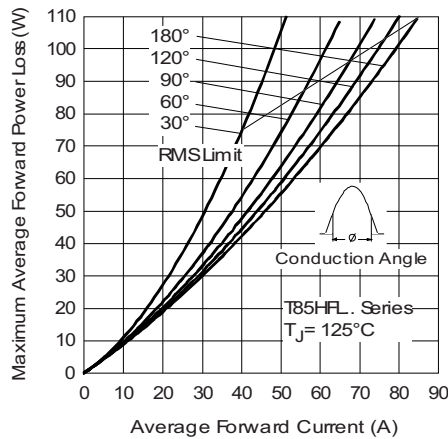


Fig. 11 - Forward Power Loss Characteristics

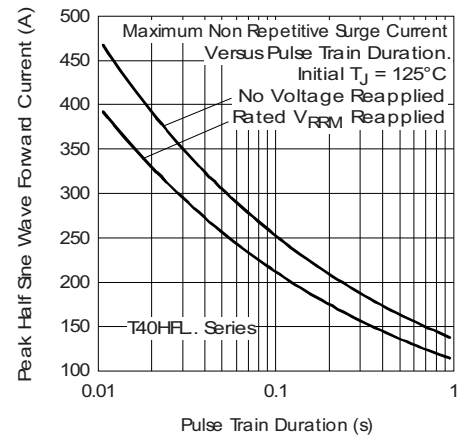


Fig. 14 - Maximum Non-Repetitive Surge Current

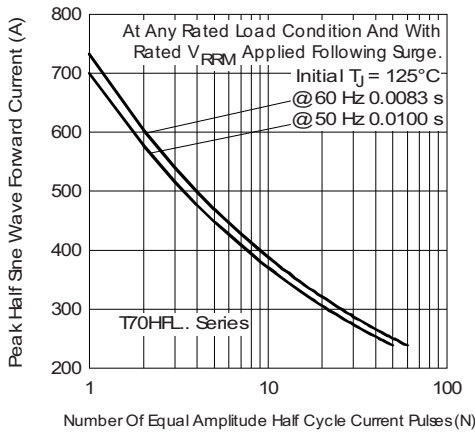


Fig. 15 - Maximum Non-Repetitive Surge Current

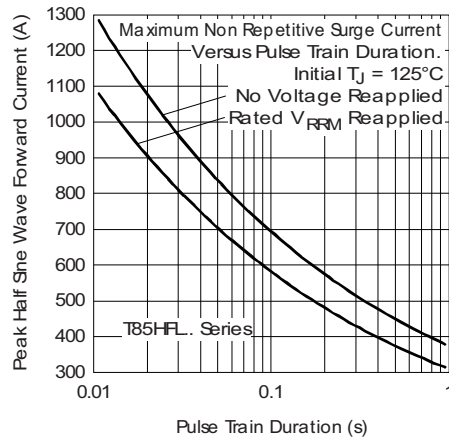


Fig. 18 - Maximum Non-Repetitive Surge Current

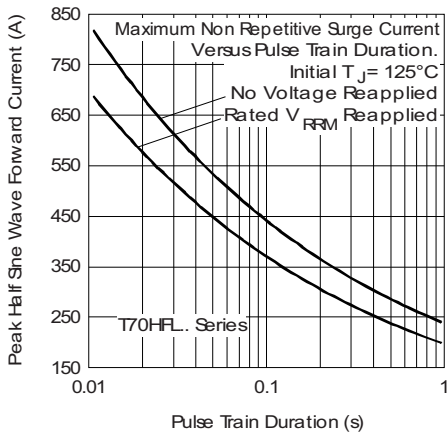


Fig. 16 - Maximum Non-Repetitive Surge Current

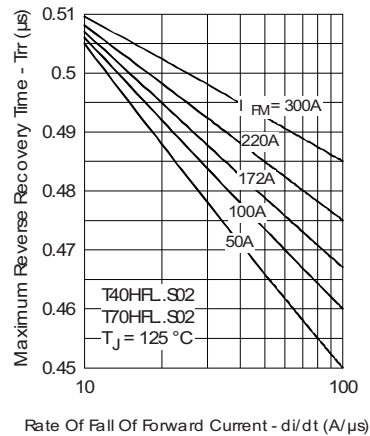


Fig. 19 - Recovery Time Characteristics

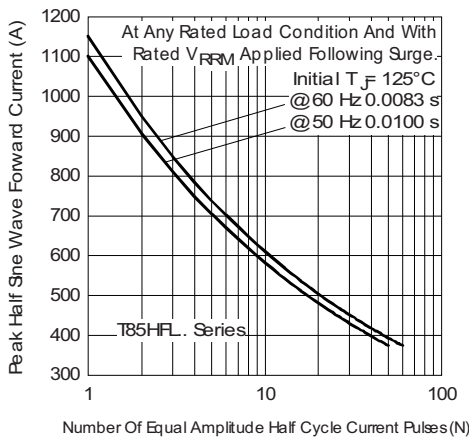


Fig. 17 - Maximum Non-Repetitive Surge Current

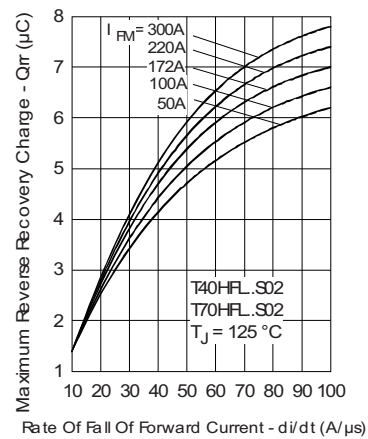


Fig. 20 - Recovery Charge Characteristics

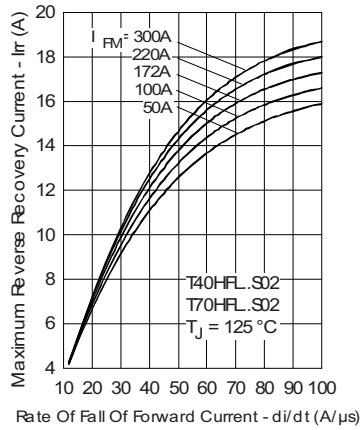


Fig. 21 - Recovery Current Characteristics

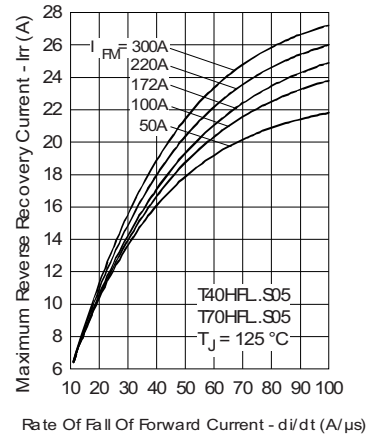


Fig. 24 - Recovery Current Characteristics

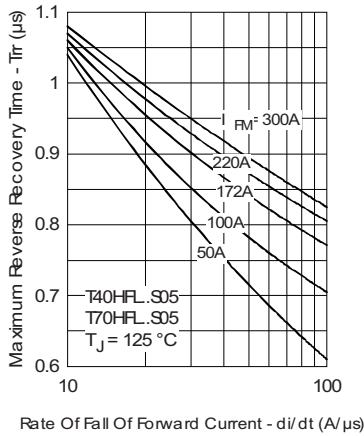


Fig. 22 - Recovery Time Characteristics

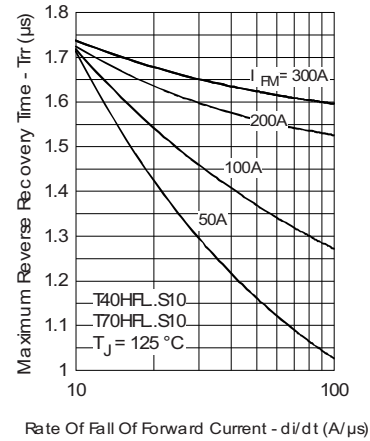


Fig. 25 - Recovery Time Characteristics

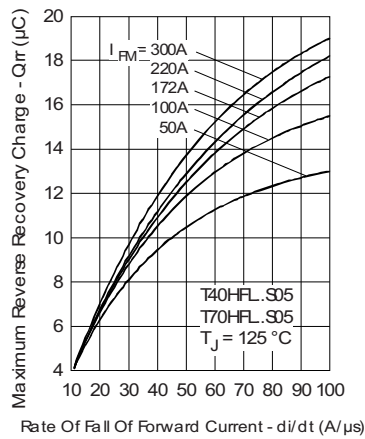


Fig. 23 - Recovery Charge Characteristics

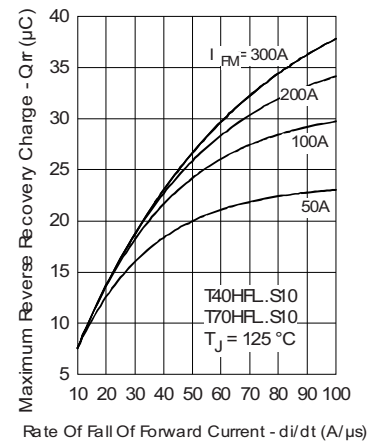


Fig. 26 - Recovery Charge Characteristics

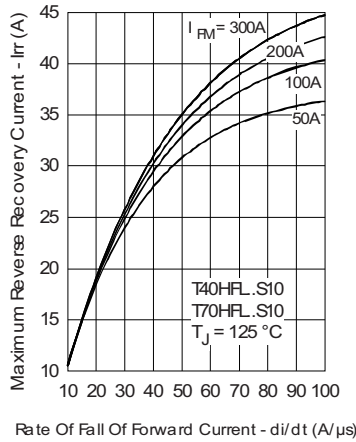


Fig. 27 - Recovery Current Characteristics

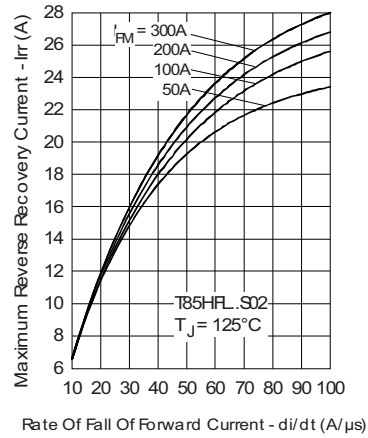


Fig. 30 - Recovery Current Characteristics

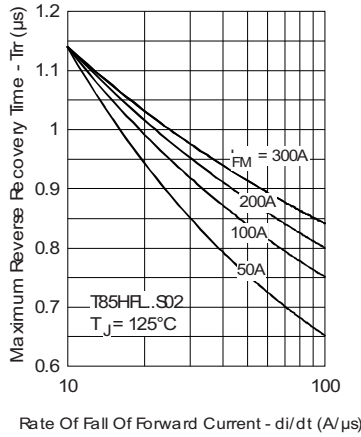


Fig. 28 - Recovery Time Characteristics

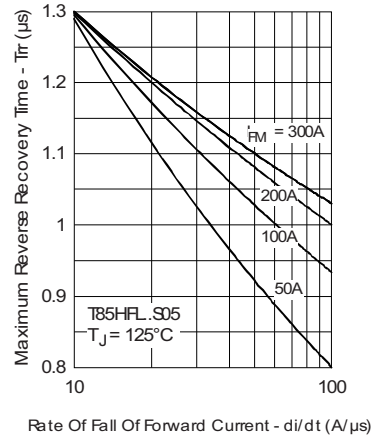


Fig. 31 - Recovery Time Characteristics

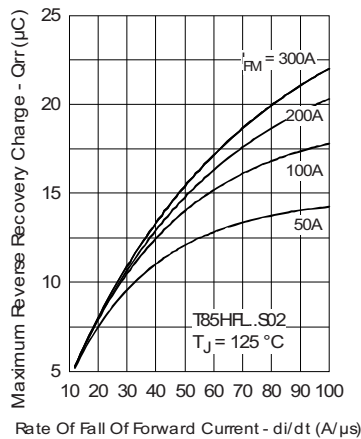


Fig. 29 - Recovery Charge Characteristics

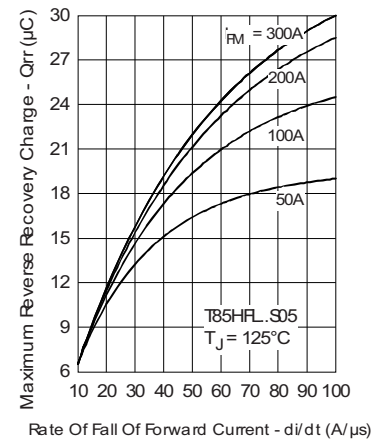


Fig. 32 - Recovery Charge Characteristics

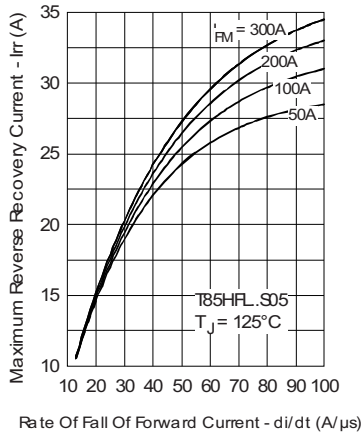


Fig. 33 - Recovery Current Characteristics

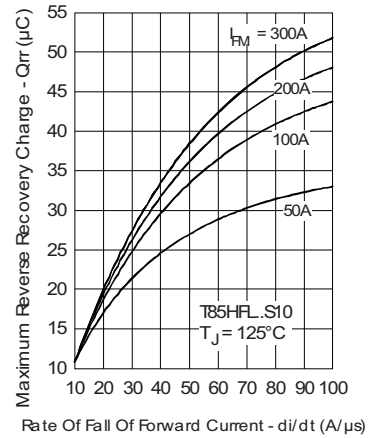


Fig. 35 - Recovery Charge Characteristics

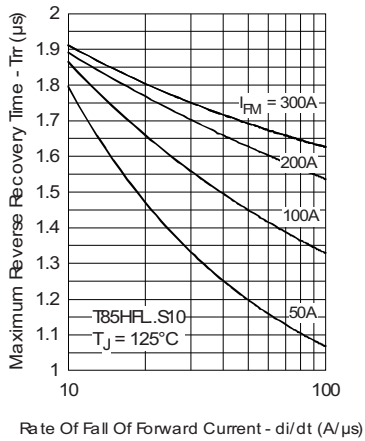


Fig. 34 - Recovery Time Characteristics

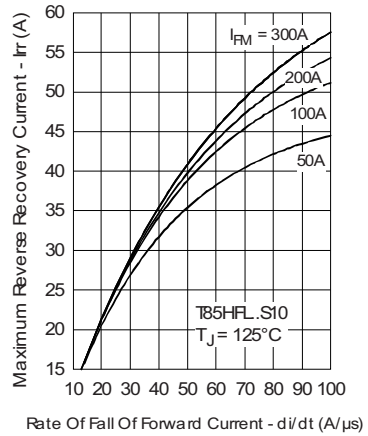


Fig. 36 - Recovery Current Characteristics

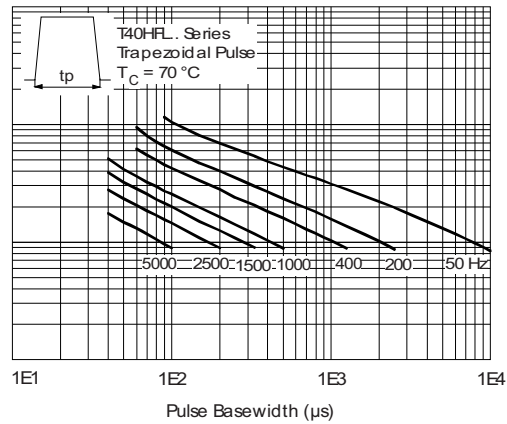
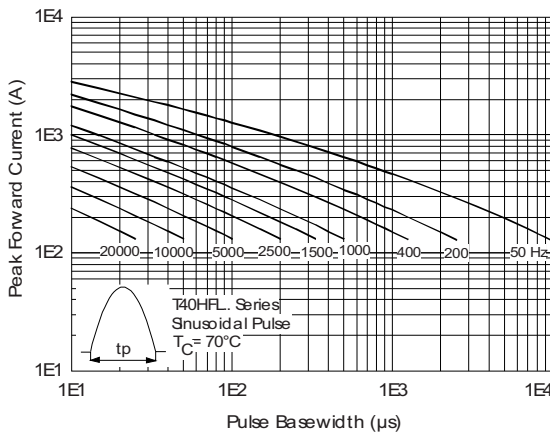


Fig. 37 - Frequency Characteristics

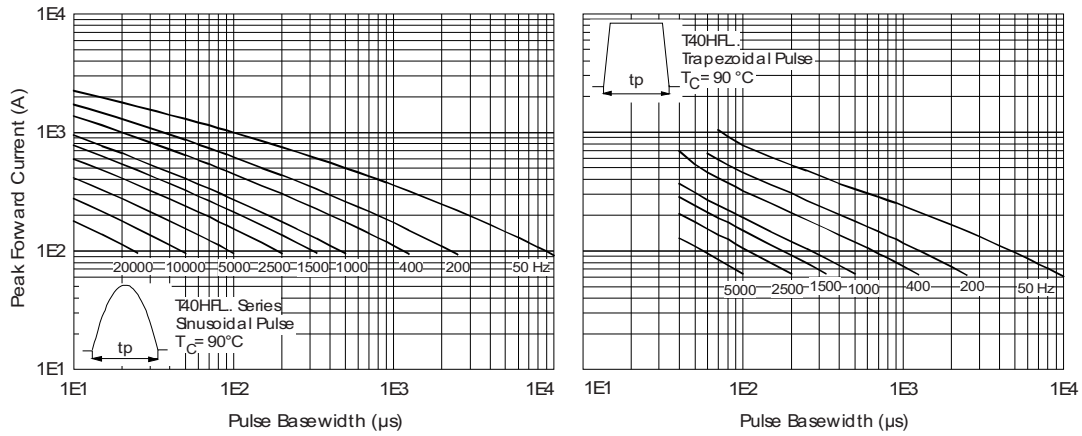


Fig. 38 - Frequency Characteristics

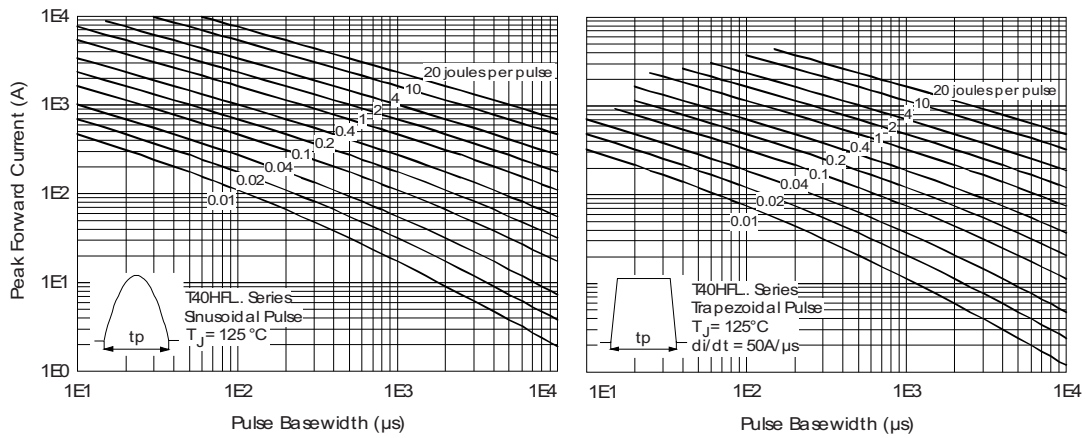


Fig. 39 - Maximum Forward Energy Power Loss Characteristics

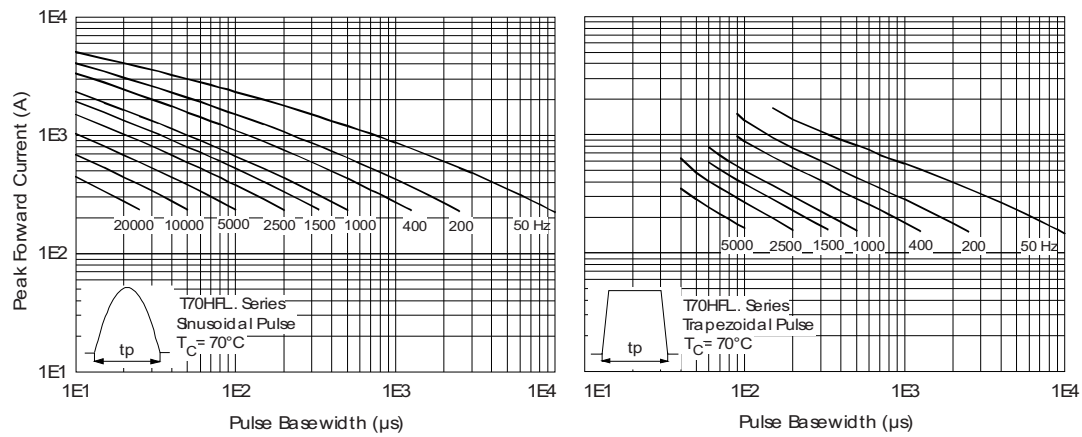


Fig. 40 - Frequency Characteristics

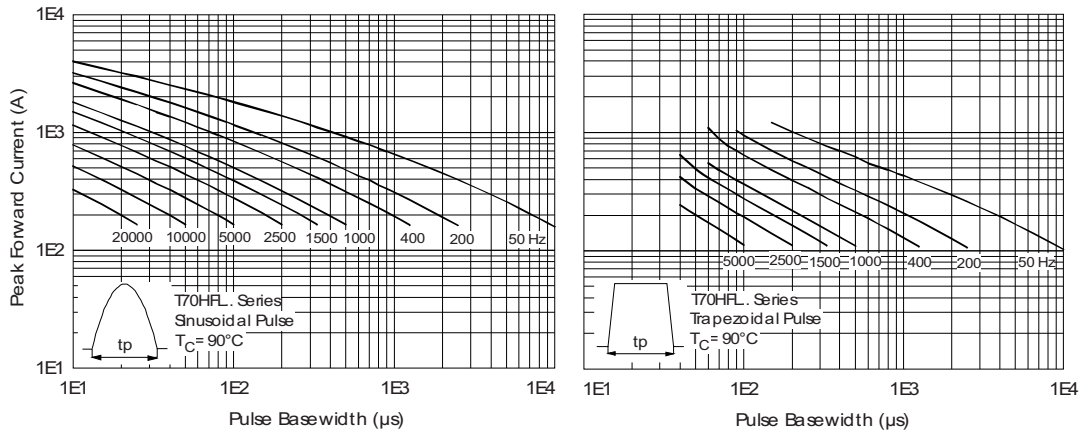


Fig. 41 - Frequency Characteristics

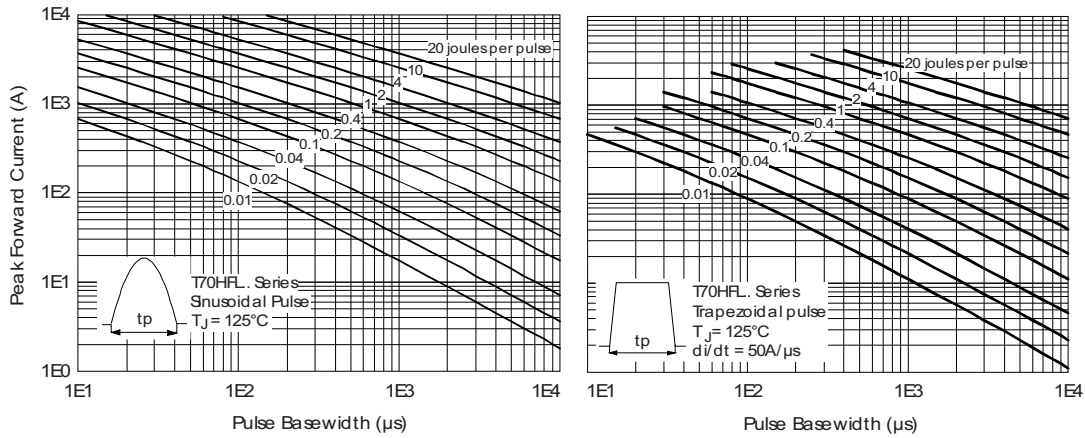


Fig. 42 - Maximum Forward Energy Power Loss Characteristics

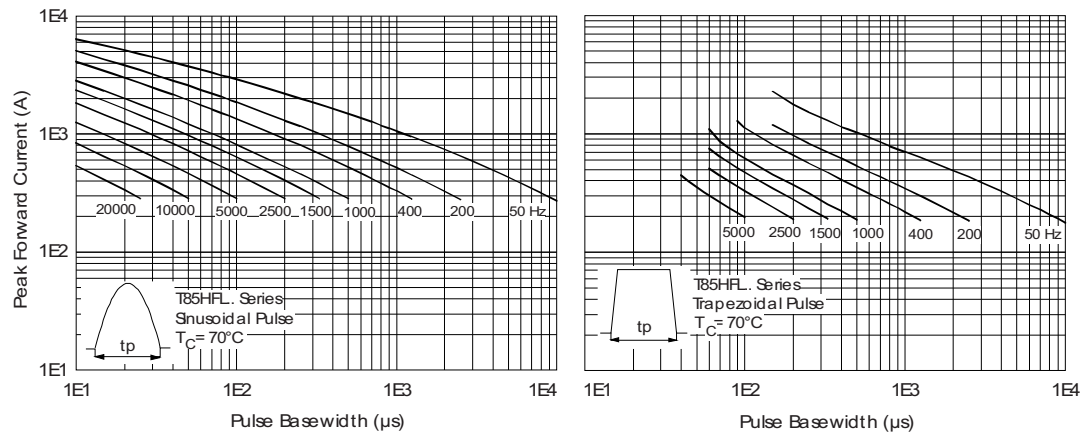


Fig. 43 - Frequency Characteristics

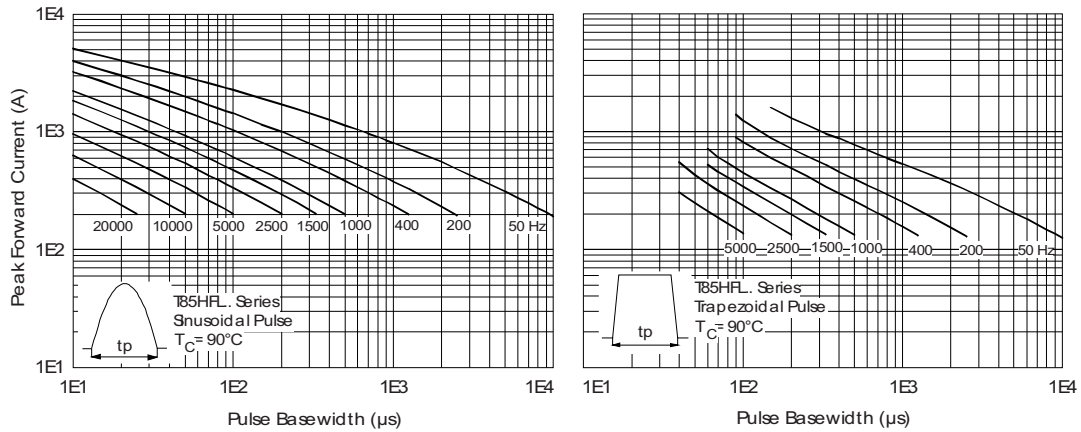


Fig. 44 - Frequency Characteristics

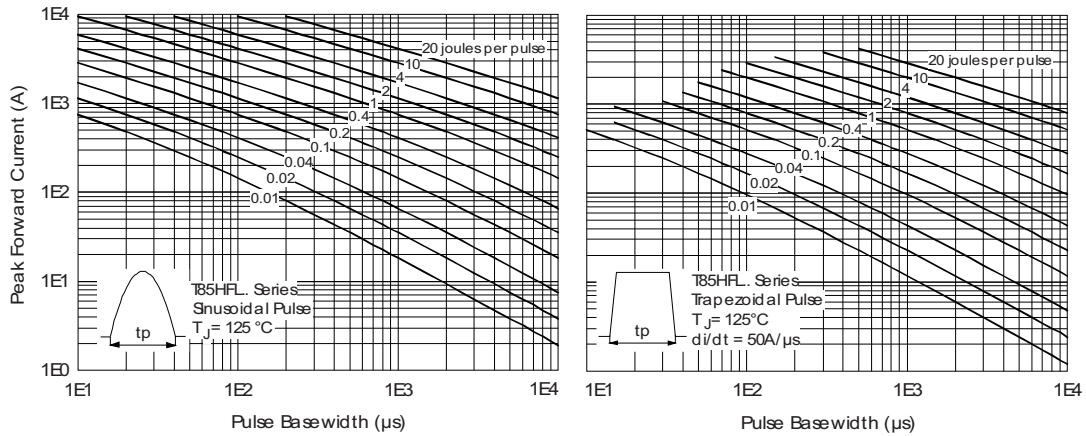


Fig. 45 - Maximum Forward Energy Power Loss Characteristics

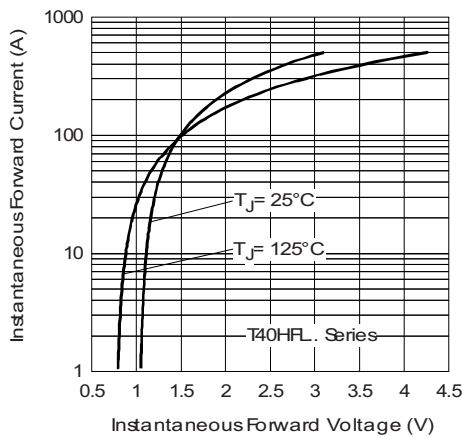


Fig. 46 - Forward Voltage Drop Characteristics

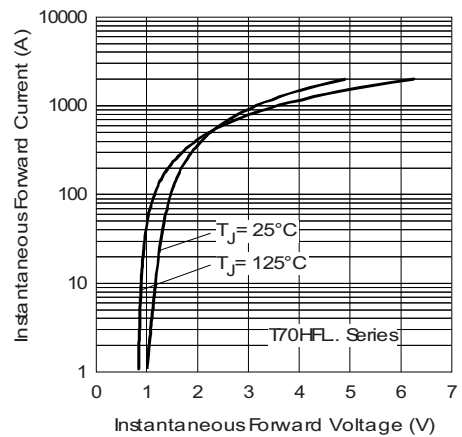


Fig. 47 - Forward Voltage Drop Characteristics

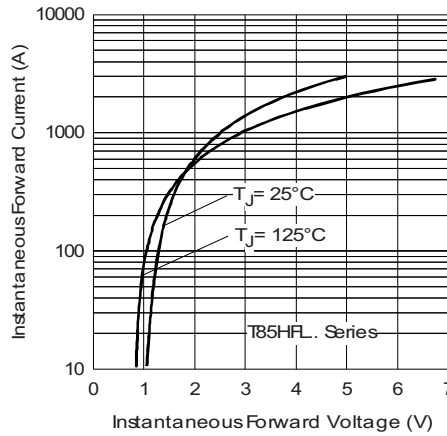


Fig. 48 - Forward Voltage Drop Characteristics

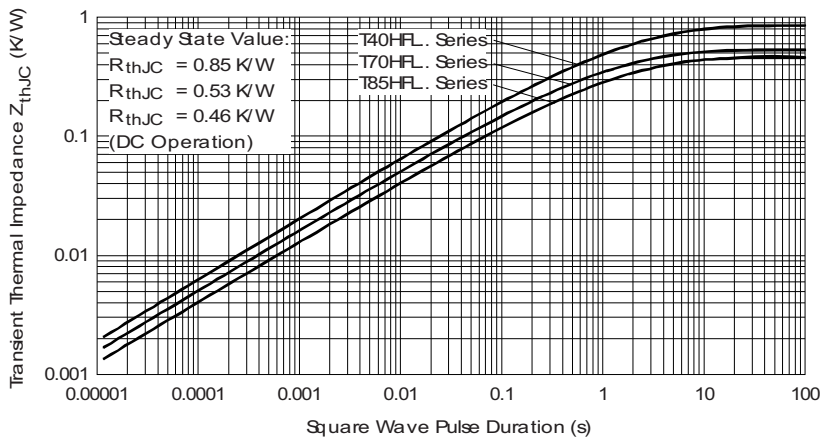
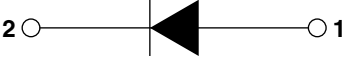


Fig. 49 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	T	40	HFL	100	S10
	①	②	③	④	⑤	⑥
	1	- Vishay Semiconductors product				
	2	- Module type				
	3	- Current rating	40 = 40 A (average)			
			70 = 70 A (average)			
			85 = 85 A (average)			
	4	- Fast recovery diode				
	5	- Voltage code x 10 = V_{RRM}				
	6	- t_{rr} code			S02 = 200 ns	
					S05 = 500 ns	
					S10 = 1000 ns	



CIRCUIT CONFIGURATION		
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Single	HFL	

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95313



D-55 T-Module Diode Standard and Fast Recovery

DIMENSIONS in millimeters (inches)



Note

- 1 = Anode
- 2 = Cathode



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.